

<b>SANYO</b>	No. 4947A	<b>LB1886V</b>
	<b>Three-Phase Brushless Motor Driver</b>	

### Overview

The LB1886V is a three-phase brushless motor driver IC that is optimal for capstan and drum motor drive in camcorders and other VCR products and for motor drive in digital audio products.

### Features

- 120° voltage linear drive scheme
- Motor voltage control based speed control provides reduced power (and thus is optimal for use in portable equipment)
- Built-in torque ripple compensation filter
- Soft switching scheme requires a smaller external capacitance (thus chip capacitors can be used)
- Built-in thermal shutdown circuit
- Built-in FG amplifier

### Specifications

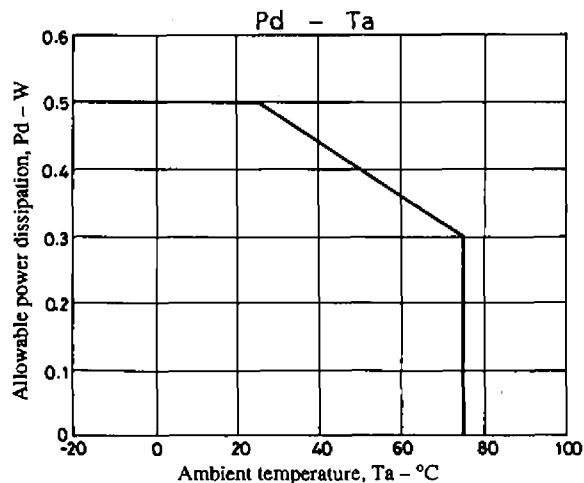
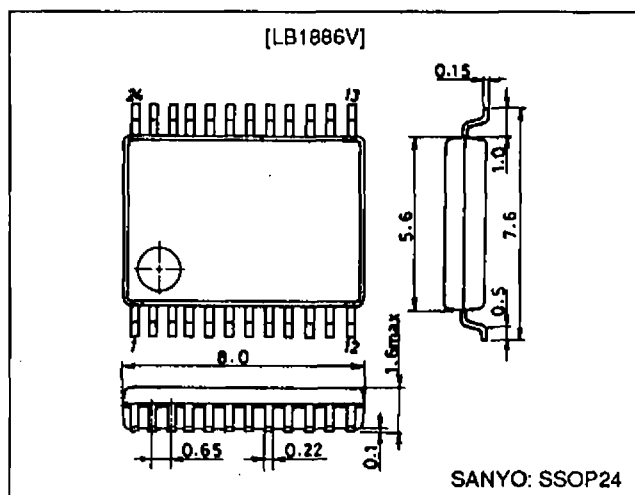
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	V <sub>CC1</sub> max		7	V
Maximum supply voltage 2	V <sub>CC2</sub> max		12	V
Maximum supply voltage 3	V <sub>S</sub> max		V <sub>CC2</sub>	V
Applied output voltage	V <sub>O</sub> max		V <sub>S</sub> + 2	V
Applied input voltage	V <sub>I</sub> max	All input pins	V <sub>CC1</sub>	V
Output current	I <sub>O</sub> max		1.0	A
Allowable power dissipation	P <sub>d</sub> max		0.5	W
Operating temperature	T <sub>opr</sub>		-20 to +75	°C
Storage temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

unit: mm

3175A-SSOP24



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Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V <sub>CC1</sub>	V <sub>CC1</sub> ≤ V <sub>CC2</sub>	4.0 to 6.0	V
Supply voltage 2	V <sub>CC2</sub>		4 to 10	V
Supply voltage 3	V <sub>S</sub>		up to V <sub>CC2</sub>	V

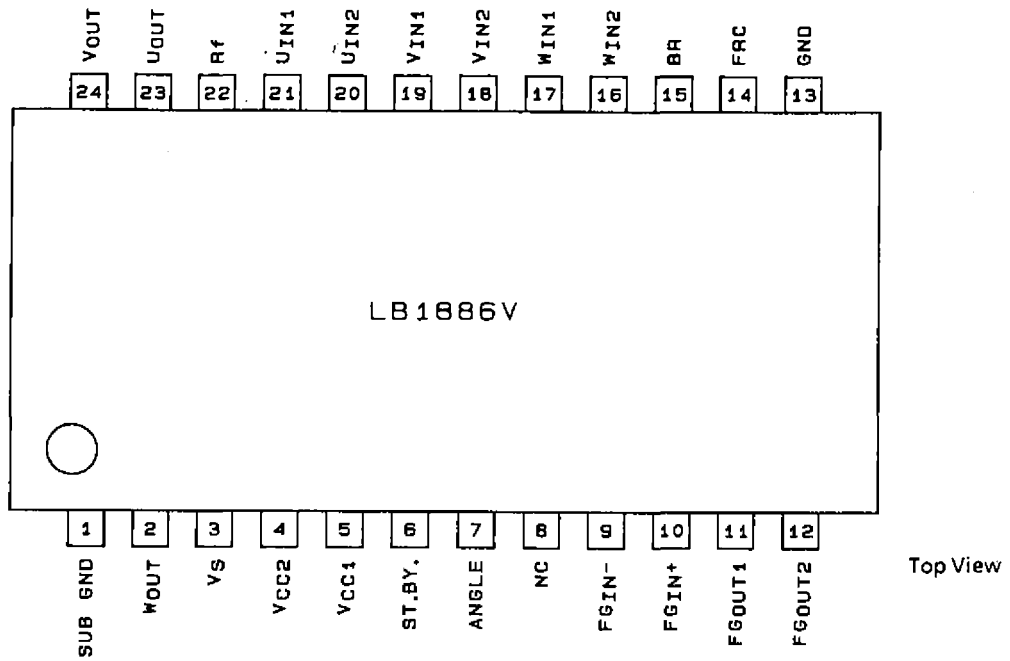
Electrical Characteristics at Ta = 25°C, V<sub>CC1</sub> = 5 V, V<sub>CC2</sub> = 7 V, V<sub>S</sub> = 3 V

Parameter	Symbol	Conditions	min	typ	max	Unit
Current drain 1	I <sub>CC1</sub>	V <sub>BR</sub> = 5 V		3.0	5.0	mA
Current drain 2	I <sub>CC2</sub>	V <sub>BR</sub> = 5 V		6.5	10.0	mA
Current drain 3	I <sub>S</sub>	V <sub>BR</sub> = 5 V, R <sub>L</sub> = ∞			5.0	mA
Quiescent current 1	I <sub>CCOQ</sub>	V <sub>STBY</sub> = 0 V			100	μA
Quiescent current 2	I <sub>SOQ</sub>	V <sub>STBY</sub> = 0 V, R <sub>L</sub> = ∞			150	μA
Output saturation voltage	V <sub>O(sat)</sub>	I <sub>OUT</sub> = 0.6 A, sink + source			1.7	V
Output transistor breakdown voltage	V <sub>O(sus)</sub>	I <sub>OUT</sub> = 20 mA, *2	12			V
Quiescent voltage	V <sub>OQ</sub>	V <sub>BR</sub> = 5 V	1.45	1.55	1.65	V
Hall amplifier input offset voltage	V <sub>H offset</sub>	*2	-5		+5	mV
Hall amplifier common mode input voltage range	V <sub>HCOM</sub>		1.4		2.8	V
Hall I/O voltage gain	G <sub>VHO</sub>	R <sub>angle</sub> = 8.2 kΩ	34.5	37.5	40.5	dB
Brake pin high level voltage	V <sub>BRH</sub>		2.0			V
Brake pin low level voltage	V <sub>BRL</sub>				0.8	V
Brake pin input current	I <sub>BRIN</sub>				120	μA
Brake pin leakage current	I <sub>BR leak</sub>				-30	μA
FRC pin high level voltage	V <sub>FRC H</sub>		2.8			μA
FRC pin low level voltage	V <sub>FRC L</sub>				1.2	μA
FRC pin input current	I <sub>FRC IN</sub>				100	μA
FRC pin leakage current	I <sub>FRC leak</sub>				-30	μA
Upper side residual voltage	V <sub>XH</sub>	I <sub>OUT</sub> = 100 mA, V <sub>CC2</sub> = 6 V, V <sub>S</sub> = 2 V	0.285		0.455	V
Lower side residual voltage	V <sub>XL</sub>	I <sub>OUT</sub> = 100 mA, V <sub>CC2</sub> = 6 V, V <sub>S</sub> = 2 V	0.350		0.440	V
Residual voltage inflection point	V <sub>SΔVX</sub>	I <sub>OUT</sub> = 100 mA, V <sub>CC2</sub> = 6 V, *2		0.9		V
Overlap	OL	V <sub>CC2</sub> = 6 V, V <sub>S</sub> = 3 V, R <sub>L</sub> = 100 Ω (Y)	69	79	89	%
Overlap vertical delta	ΔOL	V <sub>CC2</sub> = 6 V, V <sub>S</sub> = 3 V, R <sub>L</sub> = 100 Ω (Y)	-10	0	+10	%
Standby on voltage	V <sub>STBYL</sub>	*1	-0.2		+0.8	V
Standby off voltage	V <sub>STBYH</sub>		2		5	V
Standby pin bias current	I <sub>STBYIN</sub>				100	μA
Thermal protection circuit operating temperature	T <sub>TSD</sub>	*2	150	180	210	°C
Thermal protection circuit hysteresis	ΔT <sub>TSD</sub>	*2		15		°C
[FG Amplifier]						
FG amplifier input offset voltage	V <sub>FG offset</sub>		-8		+8	mV
Open loop voltage gain	G <sub>VFG</sub>	f = 10 kHz		43		dB
Source output saturation voltage	V <sub>FG OU</sub>	I <sub>O</sub> = -2 mA	3.7			V
Sink output saturation voltage	V <sub>FG OD</sub>	I <sub>O</sub> = 2 mA			1.3	V
Common mode signal rejection ratio	G <sub>HRR</sub>	*2		80		dB
FG amplifier common mode input voltage range	V <sub>FG CH</sub>		0		+3.5	V
Phase margin	φ <sub>M</sub>	*2		20		deg
Schmitt amplifier threshold voltage	V <sub>FGS SH</sub>	V <sub>FGin</sub> <sup>+</sup> = 2.5 V, when V <sub>FGout2</sub> goes from high to low	2.45	2.50	2.55	V
Schmitt amplifier hysteresis	V <sub>FGS HIS</sub>	V <sub>FGin</sub> <sup>+</sup> = 2.5 V	20	40	60	mV

Note: 1. The IC goes to the standby state when the standby pin is open.  
 2. These are design target values and are not measured.  
 The overlap standard is taken as the test standard without change.

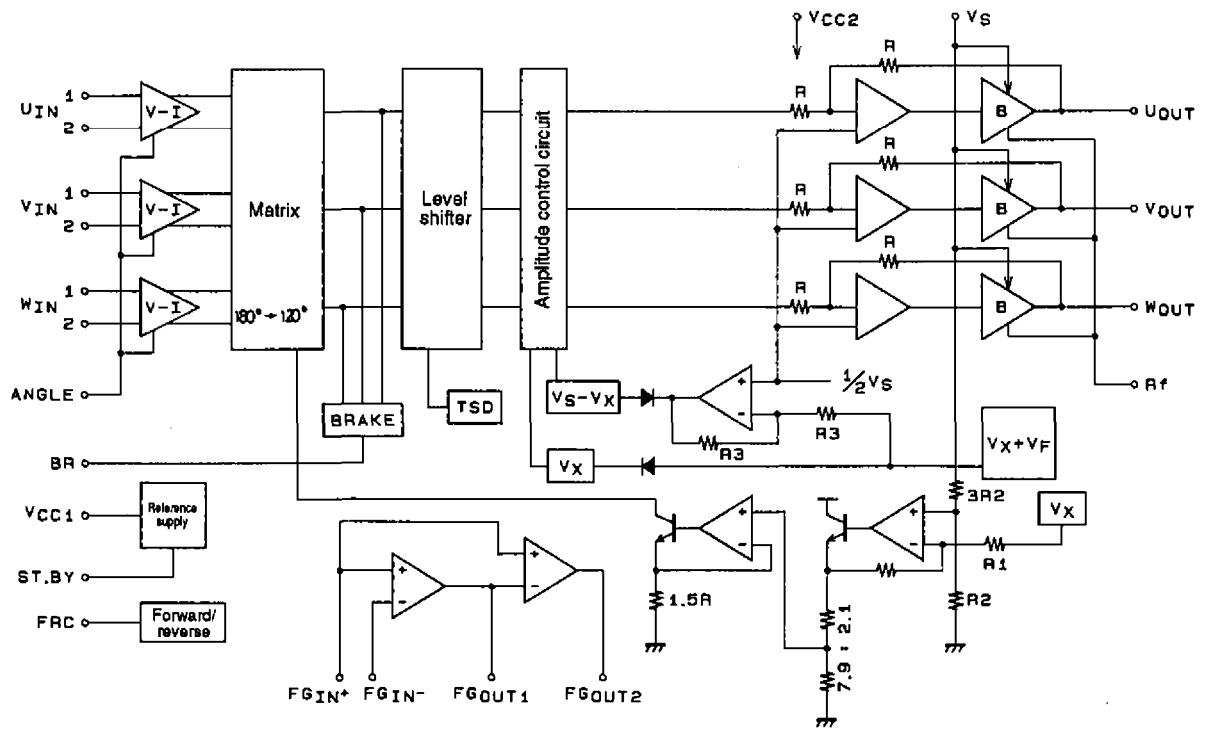
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## Pin Assignment



A02867

## Internal Equivalent Circuit Block Diagram



Pin Functions

Pin No.	Symbol	Pin voltage	Equivalent circuit	Function
3	V <sub>S</sub>	< V <sub>CC2</sub>		Supply pin that determines the output amplitude. This pin must be set lower than the V <sub>CC2</sub> voltage.
4	V <sub>CC2</sub>	4 to 10 V		Power amplifier system power supply for transistors other than those that drive the motor. Power supply voltage for control blocks other than those provided by V <sub>CC1</sub> .
5	V <sub>CC1</sub>	4 to 6 V		Power supply voltage for the Hall amplifier, forward/reverse, FG amplifier, and thermal shutdown circuits
6	ST. BY	H: 2.0 V min L: 0.8 V max (when V <sub>CC1</sub> is 5 V.)	<p>A03003</p>	All circuits are turned off by connecting this pin to ground or leaving it open. The current drain is about 0 μA in this mode. Apply 2.0 V or higher for motor drive operation.
7	ANGLE		<p>A03004</p>	Connect a resistor between this pin and ground. The Hall input/output gain can be changed by changing the value of this resistor.
9 10	FGin - FGin +	min 0 V max 3.5 V (when V <sub>CC1</sub> is 5 V.)	<p>A03005</p>	FG signal input
11	FGout1		<p>A03006</p>	FG amplifier output

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Pin No.	Symbol	Pin voltage	Equivalent circuit	Function
12	FGout2		<p>A03007</p>	FG Schmitt amplifier output
14	FRC	H: 2.8 V min L: 1.2 V max (when V <sub>CC1</sub> is 5 V.)	<p>A03008</p>	Motor forward/reverse control Low level: forward (1.2 V or lower: when V <sub>CC1</sub> = 5 V) High level: reverse (2.8 V or higher: when V <sub>CC1</sub> = 5 V)
15	BR	H: 2.0 V min L: 0.8 V max	<p>A03009</p>	Motor stop control Low level: motor drive (0.8 V or lower) High level: Motor stop (2.0 V or higher)
16 17 18 19 20 21	Win2 Win1 Vin2 Vin1 Uin2 Uin1	min 1.4 V max 2.8 V (when V <sub>CC1</sub> is 5 V.)	<p>A03010</p>	W phase Hall element input pin logic High refers to the state where W <sub>IN1</sub> > W <sub>IN2</sub> V phase Hall element input pin logic High refers to the state where V <sub>IN1</sub> > V <sub>IN2</sub> U phase Hall element input pin logic High refers to the state where U <sub>IN1</sub> > U <sub>IN2</sub>
22	Rf			Ground for the output transistors
23 24 2	Uout Vout Wout		<p>A03011</p>	Outputs
1 13	SUB GND GND			Ground for all circuits other than the output transistor

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## Truth Table

	Source → sink	Input			Forward/reverse control F/R/C
		U	V	W	
1	W phase → V phase	H	H	L	L
	V phase → W phase				H
2	W phase → U phase	H	L	L	L
	U phase → W phase				H
3	V phase → W phase	L	L	H	L
	W phase → V phase				H
4	U phase → V phase	L	H	L	L
	V phase → U phase				H
5	V phase → U phase	H	L	H	L
	U phase → V phase				H
6	U phase → W phase	L	H	H	L
	W phase → U phase				H

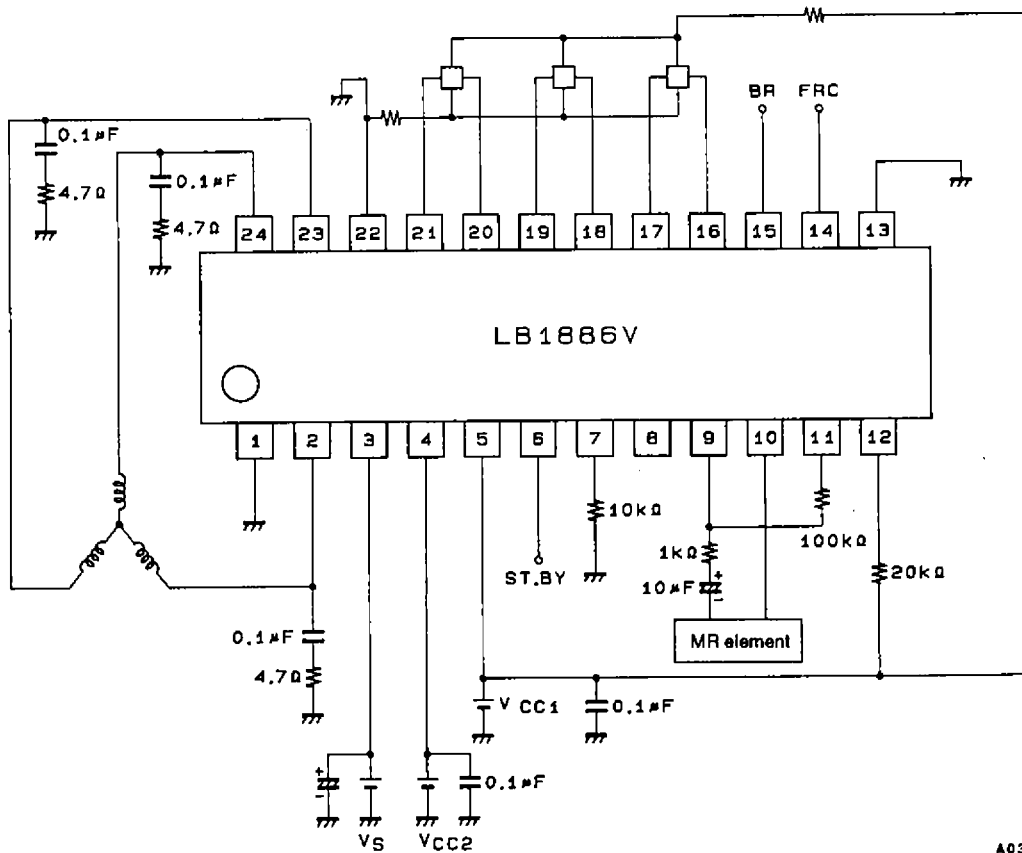
Input high: Indicates that the phase 1 input is at least 0.2 V higher than the phase 2 input for each phase.

Input low: Indicates that the phase 1 input is at least 0.2 V lower than the phase 2 input for each phase.

Forward/reverse control: High: 2.8 V to  $V_{CC1}$

Low: 0 V to 1.2 V

## Sample Application Circuit



A03012

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